

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Yi Ding

Assignee:

Mosel Vitelic, Inc.

Title:

Nonvolatile Memory Cells

With Buried Channel Transistors

Application No.:

10/632,155

Filing Date:

July 30, 2003

Examiner:

Unknown

Group Art Unit:

Unassigned

Docket No.:

M-15222 US

San Jose, California September 17, 2003

Director of USPTO P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed.

Citation of these documents shall not be construed as:

- 1. an admission that the documents are necessarily prior art with respect to the instant invention;
 - 2. a representation that a search has been made, other than as described above; or
- 3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Director of USPTO, P.O. Box 1450, Alexandria, VA 23313-1450, or September 17, 2003

MARK MUNKLA

Attorney for Applicant

Date of Signature

Respectfully submitted,

Michael Shewker

Michael Shenker Attorney for Applicant

Reg. No. 34,250

LAW OFFICES OF MacPherson, Kwoik, Chen & Theld 11,7 1762 Technology Drive, Suite 226 San Jose, CA 95140 Telephone (448) 392-926 Fax (448) 392-9262



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Yi Ding

Assignee:

Mosel Vitelic, Inc.

Title:

Nonvolatile Memory Cells

With Buried Channel Transistors

Application No.:

10/632,155

Filing Date:

July 30, 2003

Examiner:

Unknown

Group Art Unit:

Unassigned

Docket No.:

M-15222 US

San Jose, California September 17, 2003

Director of USPTO P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed.

Citation of these documents shall not be construed as:

- 1. an admission that the documents are necessarily prior art with respect to the instant invention:
 - 2. a representation that a search has been made, other than as described above; or
- 3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Director of USPTO, P.O. Box 1450, Alexandria, VA 22313-1450, on September 17, 2003.

Cour market

1 / / /

Respectfully submitted,
Michael Sheuker

Michael Shenker

Attorney for Applicant

Reg. No. 34,250

LAW OFFICES OF MacPherson, Kwok, Chen & Held LLP 1762 Technology Drive, Suite 226 San Jose, CA 95110 Telephote (408) 392-9520 Fax (408) 392-9262

U.S. Department of Commerce, Patent and Trademark Office			Atty Docket No.	Serial No.					
			M-15222 US	10/632,155					
P ENFOR	MATIO	N DISCLOSURE STATEMENT BY APPLICANT	Applicant						
0 %		(Use several sheets if necessary)	Yi Ding						
SEP 2 2 70115	DIE.		Filing Date	Group					
	\$		July 30, 2003	Unassigned					
BADEN	y	OTHER ART (Including Author, Title, Date,	Pertinent Pages, Etc.)						
	AV	AV United States Patent Application No. 10/393,212, entitled "Nonvolatile Memories And Methods Of Fabrication," Filed on March 19, 2003; Attorney Docket No.: M-12902 US. AW United States Patent Application No. 10/411,813, entitled "Nonvolatile Memories With A Floating Control of Having An Upward Protrusion," Filed on April 10, 2003; Attorney Docket No.: M-12903 US.							
	AW								
	AX United States Patent Application No. 10/393,202, entitled "Fabrication of Integrated Circuit E Structures With Protruding Features," Filed on March 19, 2003; Attorney Docket No.: M-151 AY United States Patent Application No. 10/631,941, entitled "Nonvolatile Memory Cell With Mu Floating Gates Formed After The Select Gate," Filed on July 30, 2003; Attorney Docket No.: US.								
	AZ	United States Patent Application No. 10/632,007, entitled "Arrays Of Nonvolatile Memory Cells Wherin Each Cell Has Two Conductive Floating Gates," Filed on July 30, 2003; Attorney Docket No.: M-15223 US.							
	ctric For A Nonvolatile Docket No.: M-15229								
	Dielectric In Nonvolatile 30, 2003; Attorney								
	ВС	Docket No.: M-15230 US. United States Patent Application No. 10/631,552, entitled "Nonvolatile Memories And Methods Of Fabrication," Filed on July 30, 2003; Attorney Docket No.: M-12902-1P US.							
	Cell With Multiple Filed on July 30, 2003;								
	BE								
	BF								
	BG								
	ВН								
Examiner		Date Considered							
*FYAMINED	. Initial								

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

TIC Disease			_ · · · o cc:		T			Silect 1 of 2		
U.S. Deparime	ent of Cor	mmerce, Patent and	Frademark Office		Atty Docket N			al No.		
O VP DED	ATION	I DISCE OCUDE CT	ATENDED A	POLICE AND	M-15222 US 10/632,155					
O INTOK	F-1	N DISCLOSURE STA		PPLICANT	Applicant					
SEP 2-2 7000	2	(Use several sheets	if necessary)		Yi Ding					
A JULI C					Filing Date					
KA	5				July 30, 2003		Un	nassigned		
*Evaminer	U.S. Patent Documents									
*Examiner Initial	ļ	Document Number	Date	Name	Class	Subcla	iss	Filing Date If Appropriate		
	AA									
	AB									
	AC									
 .	AD									
	AE									
~	AF									
	AG									
	AH									
	AI									
	AJ									
	AK									
	AL									
	AM									
	AN			100						
	AO									
	AP									
	AQ									
	•	OTHER A	RT (Including Aut	thor, Title, Date, Per	rtinent Pages, F	itc.)				
	AR	United States Patent Application No. 10/440,466, entitled "Fabrication Of Conductive Gates For Nonvolatile Memories From Layers With Protruding Portions," Filed on May 16, 2003; Attorney Docket No.: M-12979 US.								
	AS	United States Patent Application No. 10/440,005, entitled "Fabrication of Dielectric On A Gate Surface To Insulate The Gate From Another Element Of An Integrated Circuit," Filed on May 16, 2003; Attorney Docket No.: M-15203 US.								
	AT	United States Patent Application No. 10/440,508, entitled "Fabrication Of Gate Dielectric In Nonvolatile Memories Having Select, Floating And Control Gates," Filed on May 16, 2003; Attorney Docket No.: M-15204 US.								
	AU	United States Patent Application No. 10/440,500, entitled "Integrated Circuits With Openings that Allow Electrical Contact To Conductive Features Having Self-Aligned Edges," Filed on May 16, 2003; Attorney Docket No.: M-15205 US.								
Examiner		 	Date Considered							
*EXAMINER: citation if not i	Initial if n conforr	f reference considere mance and not considere	d, whether or not of dered. Include cop	citation is in confor by of this form with	mance with MP your communic	EP 609; Decation to ap	raw li oplica	ine through int.		